

TOSHIBA Transistor Silicon NPN Triple Diffused Type (Darlington power transistor)

# 2SD1662

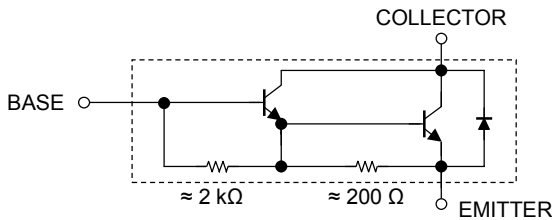
## High Current Switching Applications

- High DC current gain:  $h_{FE} = 1000$  (min) ( $V_{CE} = 3\text{ V}$ ,  $I_C = 15\text{ A}$ )
- Low collector saturation voltage:  $V_{CE(sat)} = 1.5\text{ V}$  (max) ( $I_C = 15\text{ A}$ )
- Monolithic construction with built-in base-emitter shunt resistor.

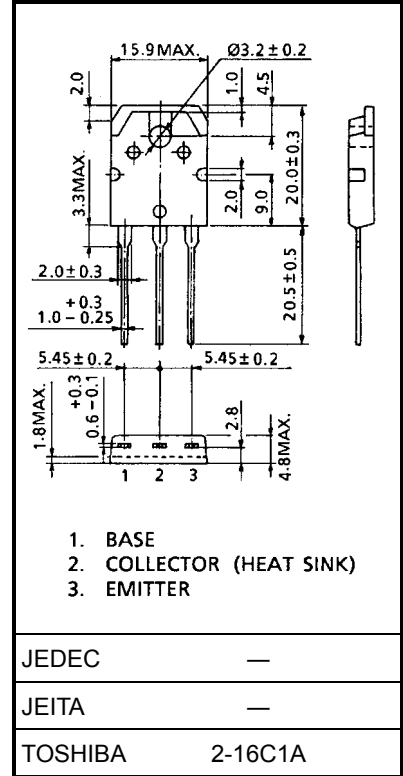
## Maximum Ratings ( $T_a = 25^\circ\text{C}$ )

Characteristics	Symbol	Rating	Unit
Collector-base voltage	$V_{CBO}$	100	V
Collector-emitter voltage	$V_{CEO}$	100	V
Emitter-base voltage	$V_{EBO}$	5	V
Collector current	$I_C$	15	A
Base current	$I_B$	1	A
Collector power dissipation ( $T_c = 25^\circ\text{C}$ )	$P_C$	100	W
Junction temperature	$T_j$	150	$^\circ\text{C}$
Storage temperature range	$T_{stg}$	-55 to 150	$^\circ\text{C}$

## Equivalent Circuit

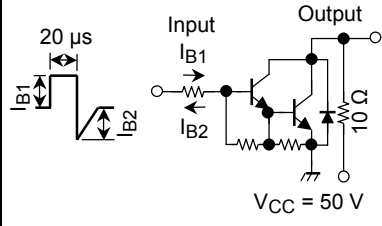


Unit: mm

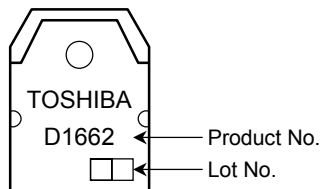


Weight: 4.7 g (typ.)

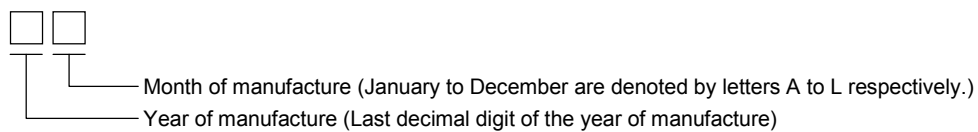
## Electrical Characteristics (Ta = 25°C)

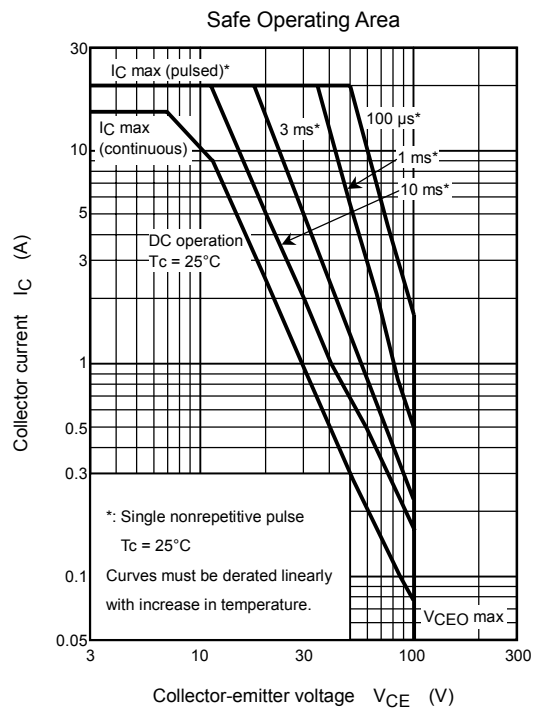
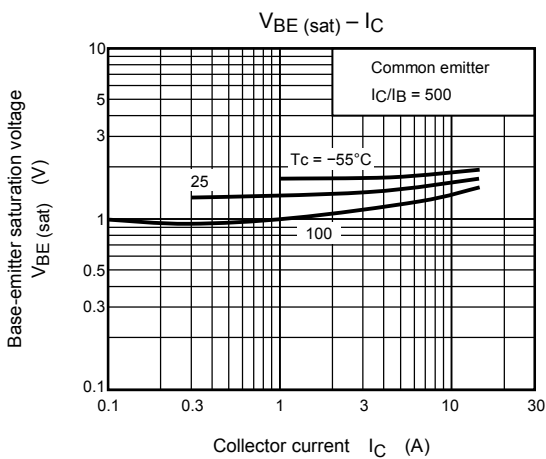
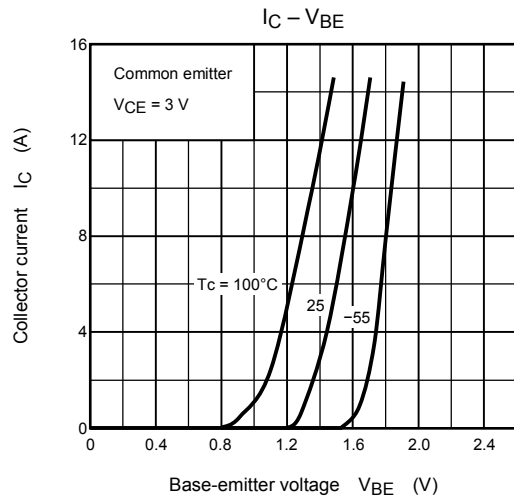
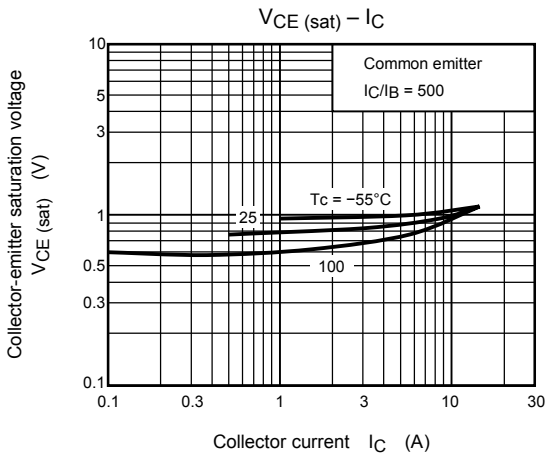
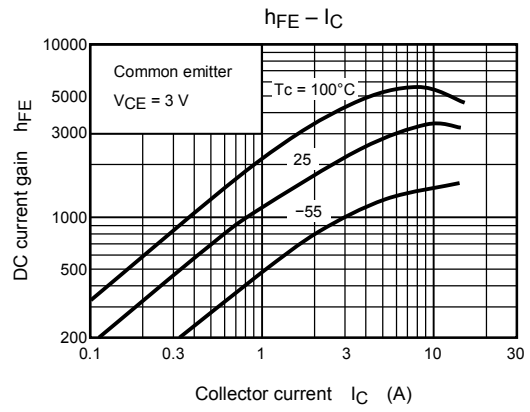
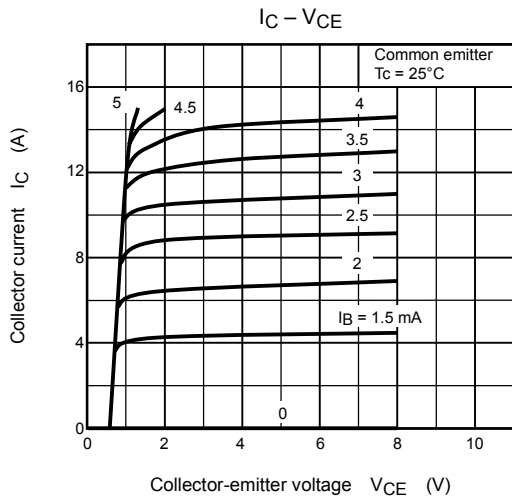
Characteristics		Symbol	Test Condition	Min	Typ.	Max	Unit
Collector cut-off current		$I_{CBO}$	$V_{CB} = 100\text{ V}, I_E = 0$	—	—	100	$\mu\text{A}$
Emitter cut-off current		$I_{EBO}$	$V_{EB} = 5\text{ V}, I_C = 0$	—	—	10	$\text{mA}$
Collector-emitter breakdown voltage		$V_{(BR)CEO}$	$I_C = 50\text{ mA}, I_B = 0$	100	—	—	$\text{V}$
DC current gain		$h_{FE}$	$V_{CE} = 3\text{ V}, I_C = 15\text{ A}$	1000	—	—	
Collector-emitter saturation voltage		$V_{CE(sat)}$	$I_C = 15\text{ A}, I_B = 0.025\text{ A}$	—	—	1.5	$\text{V}$
Base-emitter saturation voltage		$V_{BE(sat)}$		—	—	2.2	$\text{V}$
Emitter-collector forward voltage		$V_{ECF}$	$I_E = 10\text{ A}, I_B = 0$	—	—	3	$\text{V}$
Transition frequency		$f_T$	$V_{CE} = 5\text{ V}, I_C = 1\text{ A}$	—	14	—	$\text{MHz}$
Collector output capacitance		$C_{ob}$	$V_{CB} = 10\text{ V}, I_E = 0, f = 1\text{ MHz}$	—	280	—	$\text{pF}$
Switching time	Turn-on time	$t_{on}$	 <p><math>I_{B1} = -I_{B2} = 0.01\text{ A}, \text{duty cycle} \leq 1\%</math></p>	—	1	—	$\mu\text{s}$
	Storage time	$t_{stg}$		—	2	—	
	Fall time	$t_f$		—	1.5	—	

## Marking



## Explanation of Lot No.





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